NSN 5961-01-060-7299

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Fiig: A110a0



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View Online at https://aerobasegroup.com/nsn/5961-01-060-72
Internal Configuration:
Junction contact-darlington connected
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 collector to base voltage, dc
Current Rating Per Characteristic:
4.00 amperes collector current, instantaneous
Power Rating Per Characteristic:
50.0 watts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli